Dual 4-5-Input OR/NOR Gate

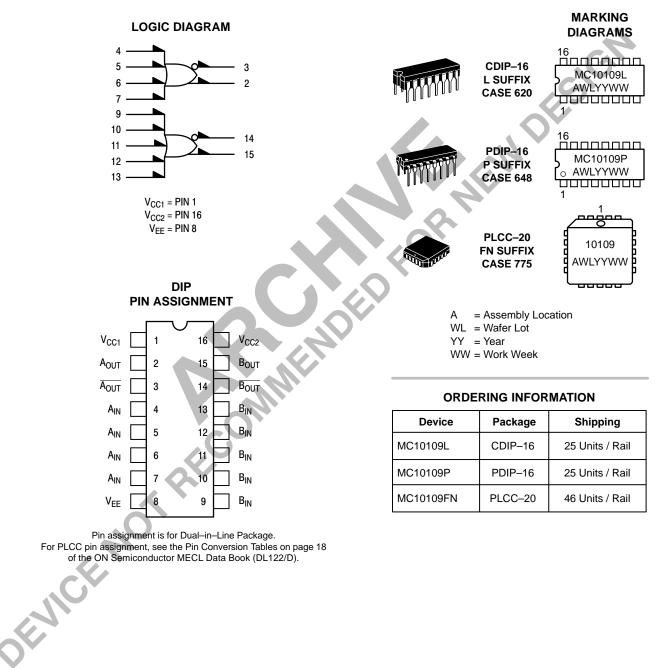
The MC10109 is a dual 4-5 input OR/NOR gate.

- $P_D = 30 \text{ mW typ/gate}$ (No Load)
- $t_{pd} = 2.0 \text{ ns typ}$
- t_r , $t_f = 2.0$ ns typ (20%-80%)



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ELECTRICAL CHARACTERISTICS

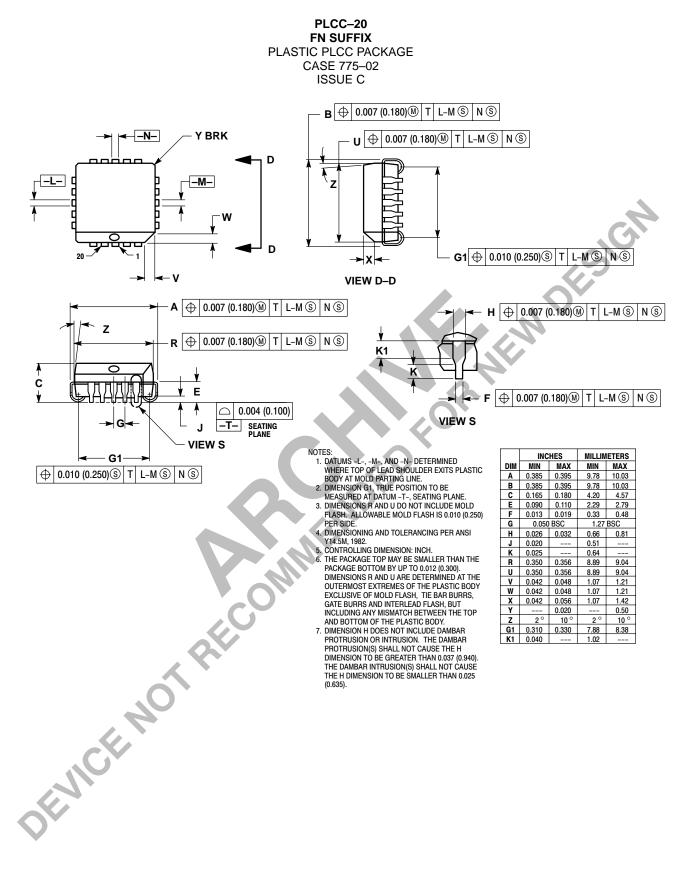
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Characteristic		D1-	Test Limits				-			
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	Characteristic			-3	0°C		+25°C		+8	5°C	
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$		Symbol		Min	Max	Min	Тур	Max	Min	Max	Un
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	Power Supply Drain Current	Ι _Ε	8		15		11	14		15	mAo
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	Input Current	I _{inH}	4		425			265		265	μΑσ
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$		l _{inL}	4	0.5		0.5			0.3		μΑσ
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	Output Voltage Logic 1	V _{OH}									Vd
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Output Voltage Logic 0	V _{OL}									Vd
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	Threshold Voltage Logic 1	V _{OHA}									Vd
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Threshold Voltage Logic 0	V _{OLA}	2 3							-1.595 -1.595	Vd
t_{4-2-21.03.71.02.02.91.03.7t_{4-3+}31.03.71.02.02.91.03.7Rise Time(20 to 80%) t_{2+} 21.14.01.12.03.31.14.0Fall Time(20 to 80%) t_{2-} 21.14.01.12.03.31.14.0	Switching Times (50 Ω Load)										ns
t3+ 3 1.1 4.0 1.1 2.0 3.3 1.1 4.0 Fall Time (20 to 80%) t_{2-} 2 1.1 4.0 1.1 2.0 3.3 1.1 4.0 Fall Time (20 to 80%) t_{2-} 2 1.1 4.0 1.1 2.0 3.3 1.1 4.0 t3- 3 1.1 4.0 1.1 2.0 3.3 1.1 4.0	Propagation Delay	t ₄₋₂₋ t ₄₊₃₋	2 3	1.0 1.0	3.7 3.7	1.0 1.0	2.0 2.0	2.9 2.9	1.0 1.0	3.7 3.7	
t ₃₋ 3 1.1 4.0 1.1 2.0 3.3 1.1 4.0	Rise Time (20 to 80%)										
	Fall Time (20 to 80%)										
		1	\$		ND						
	OFNICEN										

ELECTRICAL CHARACTERISTICS (continued)

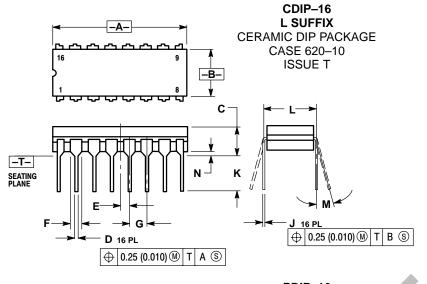
		TEST VOLTAGE VALUES (Volts)							
		@ Test Te	mperature	V _{IHmax}	V _{ILmin}	V _{IHAmin}	V _{ILAmax}	V _{EE}	
			–30°C	-0.890	-1.890	-1.205	-1.500	-5.2	
			+25°C	-0.810	-1.850	-1.105	-1.475	-5.2	
			+85°C	-0.700	-1.825	-1.035	-1.440	-5.2	
			Pin	TEST V	OLTAGE AP	PLIED TO PI	NS LISTED I	BELOW	<i></i>
Characteristic		Symbol	Under Test	V _{IHmax}	V _{ILmin}	V _{IHAmin}	V _{ILAmax}	V _{EE}	(V _{CC}) Gnd
Power Supply Drain	Current	Ι _Ε	8					8	1, 16
Input Current		I _{inH}	4	4				8	1, 16
		I _{inL}	4		4			8	1, 16
Output Voltage	Logic 1	V _{OH}	2 3	4				8 8	1, 16 1, 16
Output Voltage	Logic 0	V _{OL}	2 3	4				8 8	1, 16 1, 16
Threshold Voltage	Logic 1	V _{OHA}	2 3			4	4	8 8	1, 16 1, 16
Threshold Voltage	Logic 0	V _{OLA}	2 3			4	4	8 8	1, 16 1, 16
Switching Times	(50 Ω Load)					Pulse In	Pulse Out	–3.2 V	+2.0 V
Propagation Delay		t ₄₊₂₊ t ₄₋₂₋ t ₄₊₃₋ t ₄₋₃₊	2 2 3 3			4 4 4 4	2 2 3 3	8 8 8 8	1, 16 1, 16 1, 16 1, 16
Rise Time	(20 to 80%)	t ₂₊ t ₃₊	2 3			4 4	2 3	8 8	1, 16 1, 16
Fall Time	(20 to 80%)	t ₂₋ t ₃₋	2 3			4 4	2 3	8 8	1, 16 1, 16

ts 3 4 2 8 1 1 6 1 1 6 1 1 6 1 1 6 1 1 6 1 1 6 1 1 6 1 1 6

PACKAGE DIMENSIONS



PACKAGE DIMENSIONS



NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: INCH.
DIMENSION L TO CENTER OF LEAD WHEN FOOMED DRAWLES

DIMENSION LTO CENTER OF LEAD WHEN FORMED PARALLEL.
DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.750	0.785	19.05	19.93		
В	0.240	0.295	6.10	7.49		
С		0.200		5.08		
D	0.015	0.020	0.39	0.50		
Е	0.050 BSC		1.27 BSC			
F	0.055	0.065	1.40	1.65		
G	0.100 BSC		2.54 BSC			
Н	0.008	0.015	0.21	0.38		
Κ	0.125	0.170	3.18	4.31		
Г	0.300 BSC		7.62 BSC			
Μ	0 °	15 °	0 °	15°		
Ν	0.020	0.040	0.51	1.01		

-A-<u>ሳ ስ ስ ስ</u> 16 в 0 L $\Box \Box$ ι, հո - C S -T- SEATING PLANE H G **D** 16 PL

PDIP-16 **P SUFFIX** PLASTIC DIP PACKAGE CASE 648-08 ISSUE R

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL. 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH. 5. ROUNDED CORNERS OPTIONAL

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.740	0.770	18.80	19.55		
В	0.250	0.270	6.35	6.85		
C	0.145	0.175	3.69	4.44		
D	0.015	0.021	0.39	0.53		
F	0.040	0.70	1.02	1.77		
G	0.100	BSC	2.54	BSC		
Н	0.050 BSC		1.27 BSC			
J	0.008	0.015	0.21	0.38		
K	0.110	0.130	2.80	3.30		
L	0.295	0.305	7.50	7.74		
Μ	0°	10 °	0 °	10 °		
S	0.020	0.040	0.51	1.01		

Notes

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Notes

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